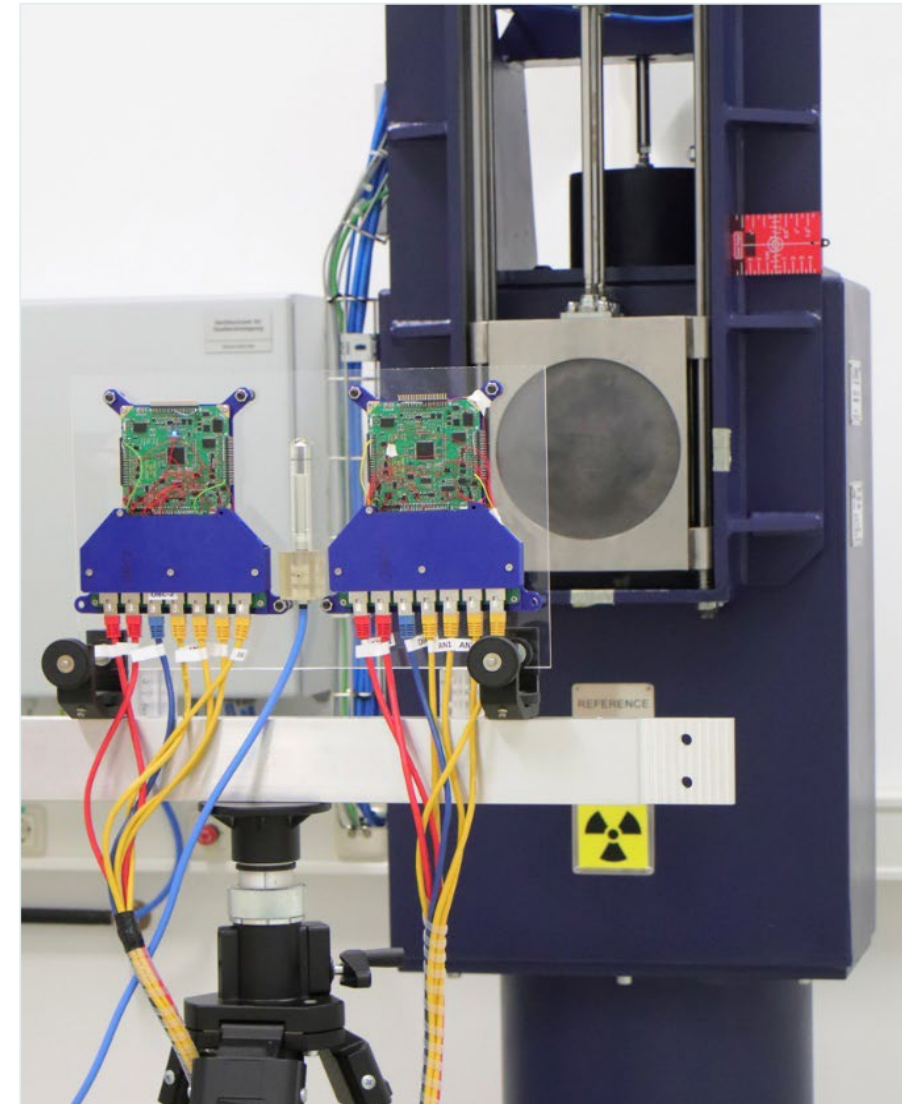


Practical Best Practices in Total Ionizing Dose Testing for Space Applications

Christoph Tscherne
Seibersdorf Laboratories

Workshop on Small Satellites: Environmental
Testing in New Space
Wiener Neustadt, 10.03.2026

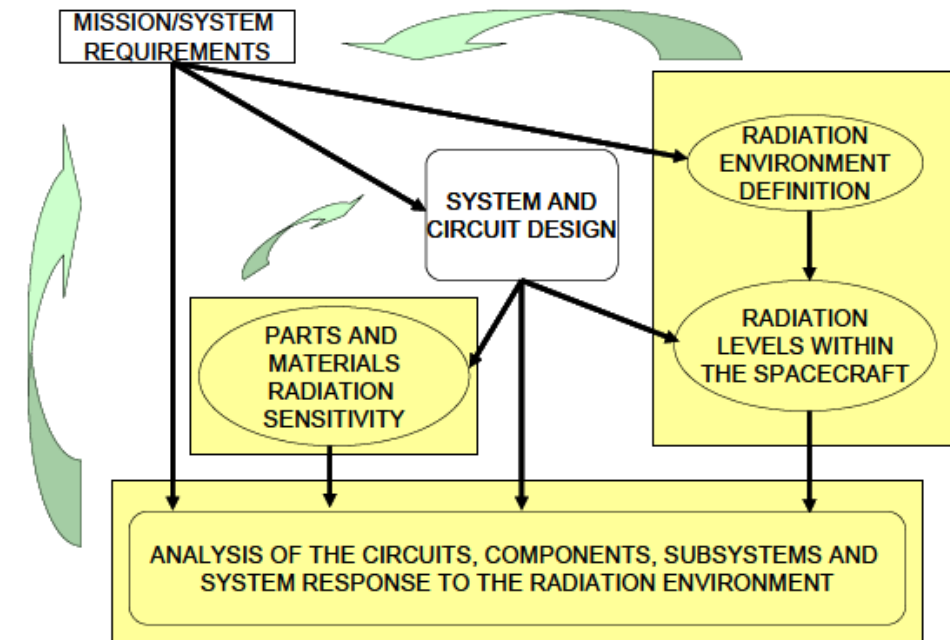


What is Radiation Hardness Assurance (RHA)?

“RHA consists of all activities undertaken to ensure that the **electronics** of a space system perform to their **specification** after exposure to the space **radiation environment**.”

RHA has implications on

- part selection
- system requirements and operations
- system and subsystems circuit design
- spacecraft layout



RHA process overview

From: ECSS-Q-ST-60-15C

Space Radiation Environment

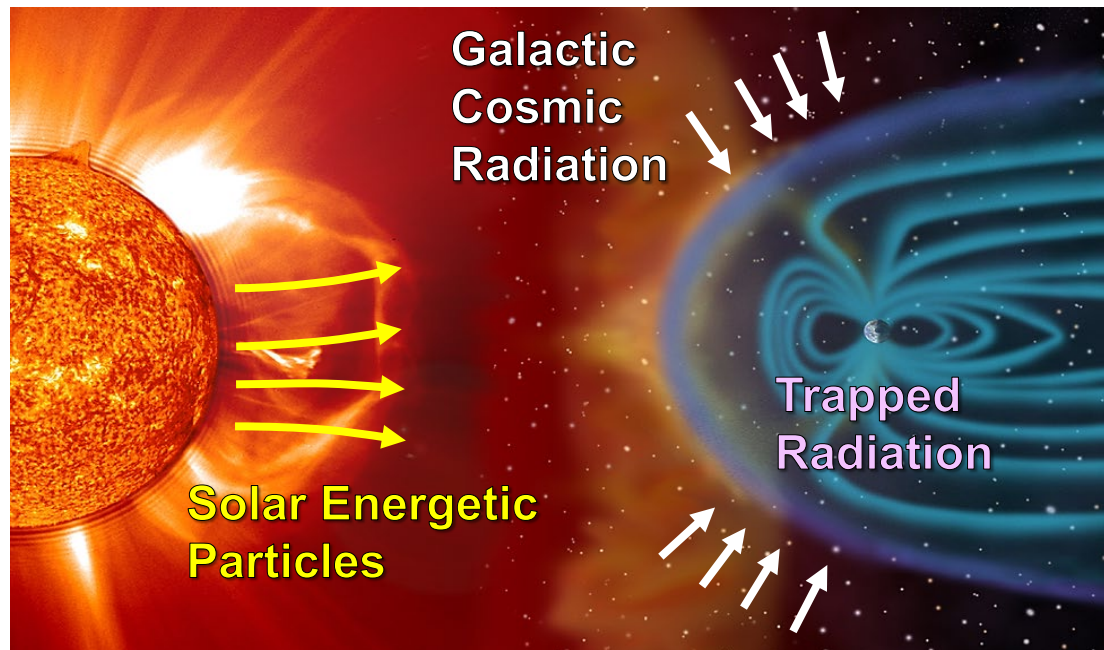
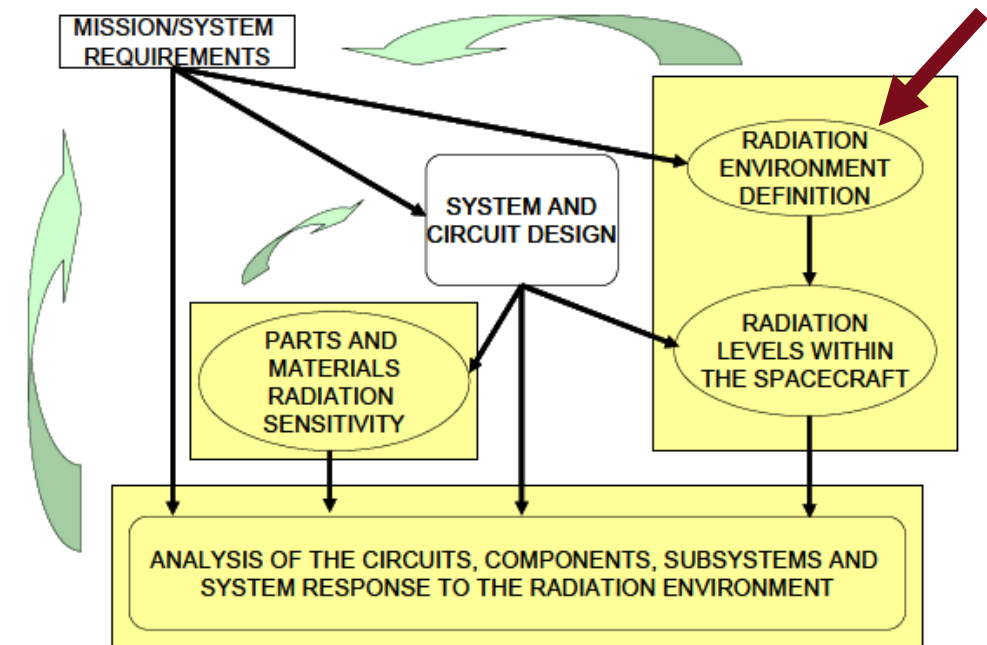


Image Credit: NASA/SOHO



RHA process overview

Main Radiation Effects on Components

Solar Particles



Image Credit: ESA

Cosmic Radiation



Image Credit: NASA

Trapped Particles

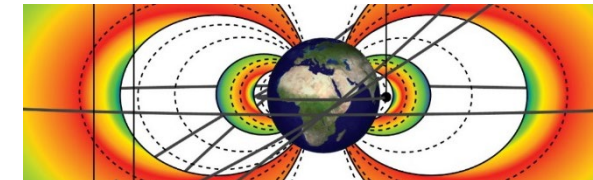
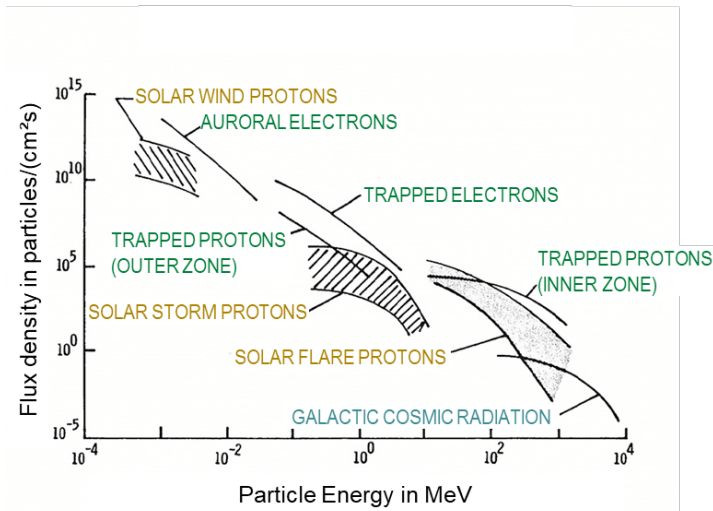
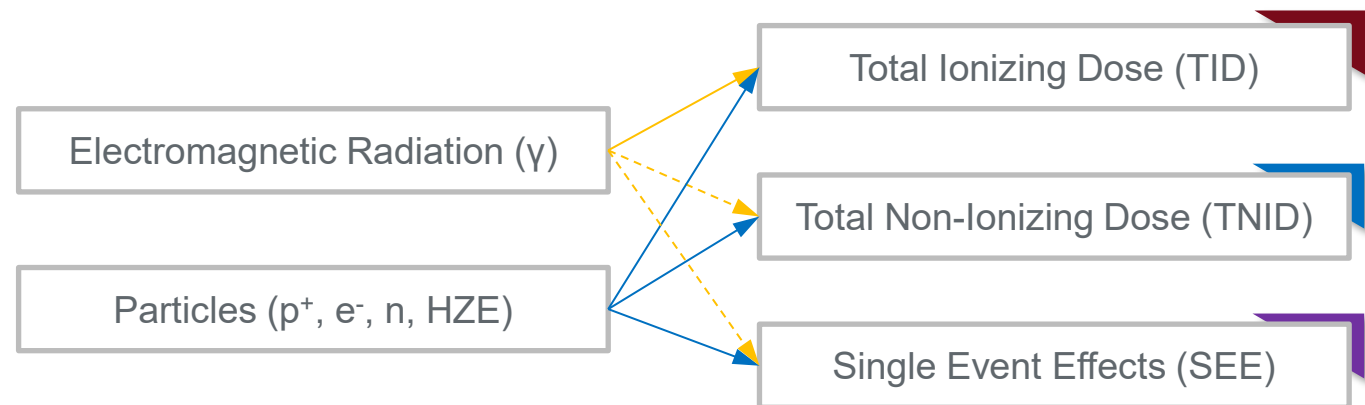


Image Credit: fp7-spacecast.eu



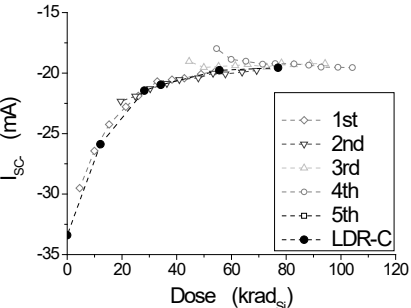
Wilson (1978) University of California, 15 Sept 1978, pp 33–116



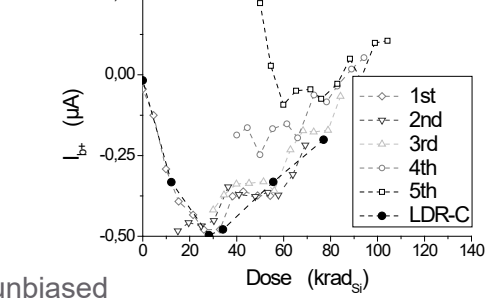
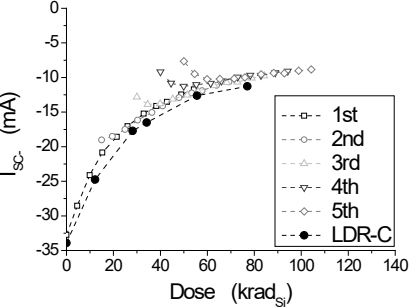
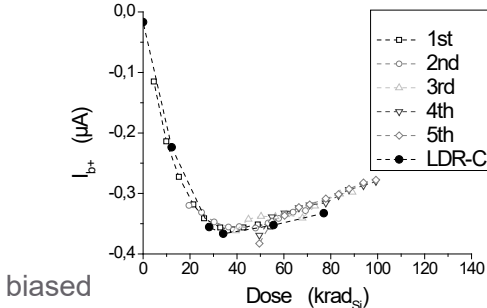
Total Ionizing Dose (TID) Effects

Electric Effects

LM324AN: I_{SC-} , I_{b+}

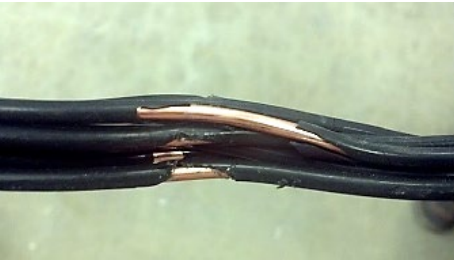
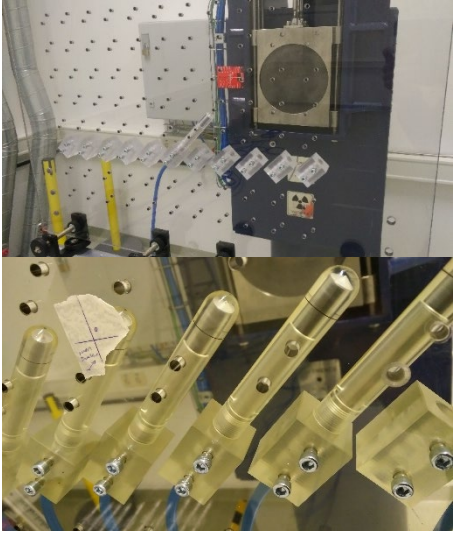


Parameter Degradation



<http://eldrs.net/>

Optical /Mechanical Effects



<https://allthingsnuclear.org/dlochbaum/fission-stories-144-not-minding-the-fort?>

Radiation Testing Standards

ECSS

*European Cooperation for
Space Standardization*

MIL-STD

*U.S. Department of
Defense*

JEDEC

*Solid State Technology
Association*

IEC

*International
Electrotechnical
Commission*

ASTM

*(formerly) American Society
for Testing and Materials*

ANSI

*American National
Standards Institute*

ESCC

*European Space
Components Coordination*

TID Hardness Assurance (ESCC-Q-ST-60-15C)

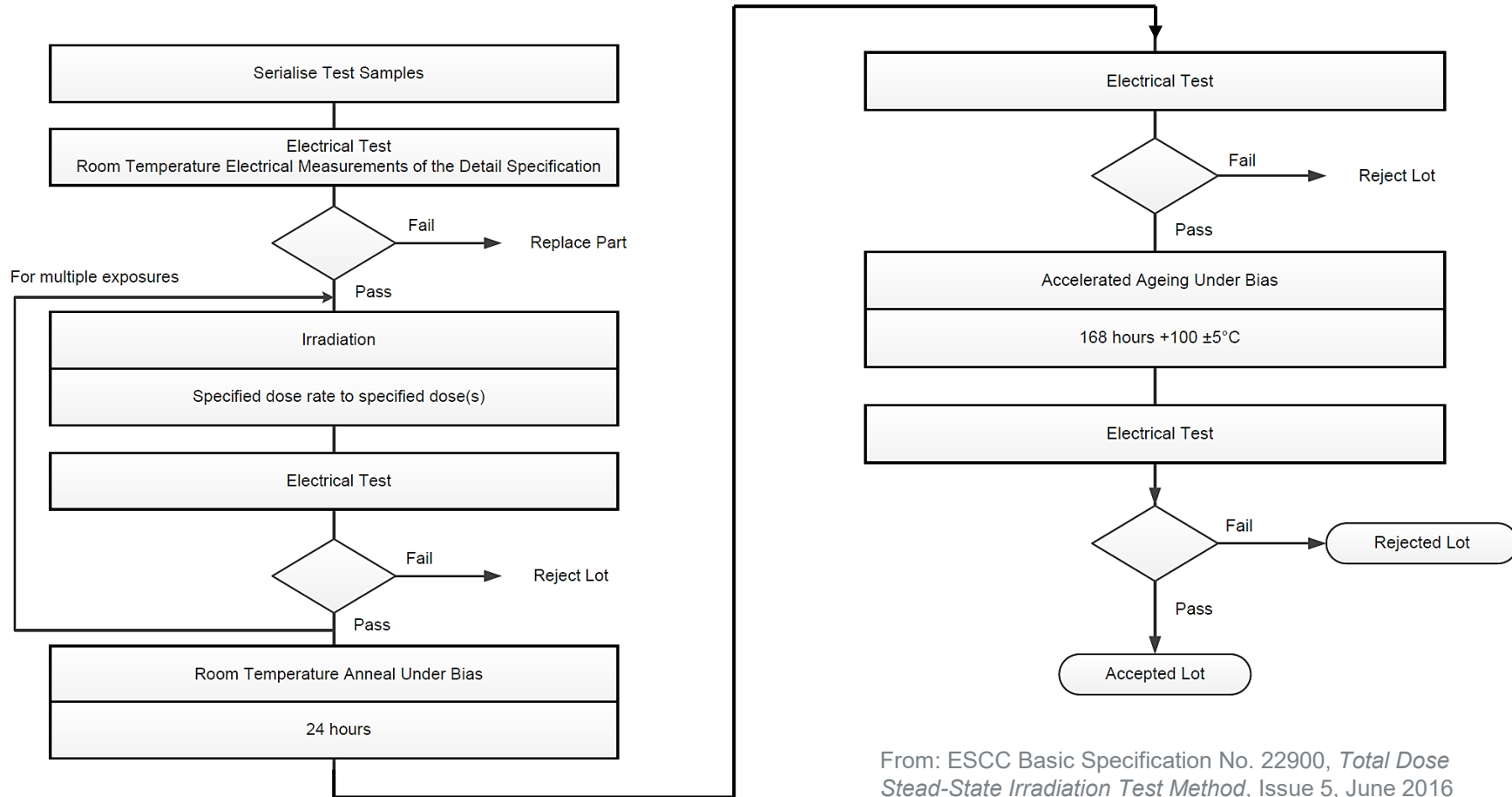
- TID test data used to assess TIDS shall comply with the following rules to be acceptable:
 - Tests are performed in conformance to **ESCC 22900, MIL-STD 883 method 1019, or MIL-STD-750 method 1019**, and
 - Devices that contain **bipolar transistors** are tested at a **dose rate** of 36 rad/h to 360 rad/h, and
 - **Tested** parts are manufactured with technology **identical** to the technology of **flight** parts: same process, same diffusion mask, and same wafer fabrication facility
 - **Bias conditions** are worse or equivalent to the application
- If acceptable component TID test data does not exist, ground testing shall be performed in conformance to **ESCC 22900**
- **Radiation Source: Co-60** (ESCC, MIL-STD) or electron beam (ESCC)

TID Sensitive Components (ESCC-Q-ST-60-15C)

Table 5-1: EEE part families potentially sensitive to TID

EEE part family	Sub family	TIDL
Diodes	Voltage reference, Zener	all
	Switching, rectifier, Schottky	> 300 krad-Si eq.
Diodes microwave		> 300 krad-Si eq.
Integrated Circuits		all
GaAs Integrated Circuits		> 300 krad-Si eq.
Oscillators (hybrids)		all
Charge Coupled devices (CCD)		all
Opto discrete devices, Photodiodes, LED, Phototransistors, Opto couplers		all
Transistors (MOS and bipolar)		all
GaAs Transistors		> 300 krad-Si eq.
Hybrids containing active parts		all

TID Hardness Assurance Testing Procedure



From: ESCC Basic Specification No. 22900, *Total Dose Stead-State Irradiation Test Method*, Issue 5, June 2016

TEC-Laboratory (Testing of Electronic Components)

EN ISO/IEC 17025 Accredited TID Assurance Testing at Seibersdorf Laboratories

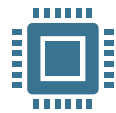




AEROSPACE RADIATION COMPETENCE CENTER

by Seibersdorf Laboratories

Space Service Portfolio



RHA Testing Laboratory

- TID – Testing at SL TEC-Laboratory
- TNID – Testing with partners
- SEE – Testing at SL and partners

Radiation Analyses

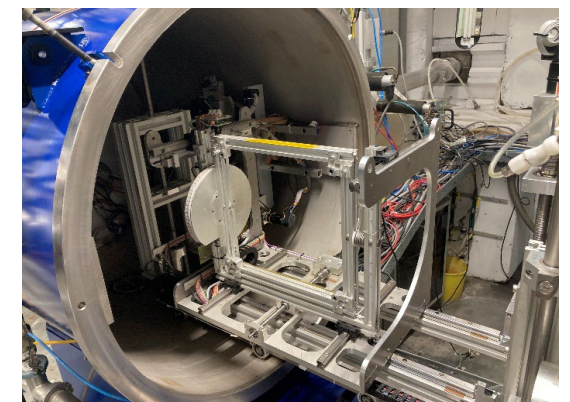
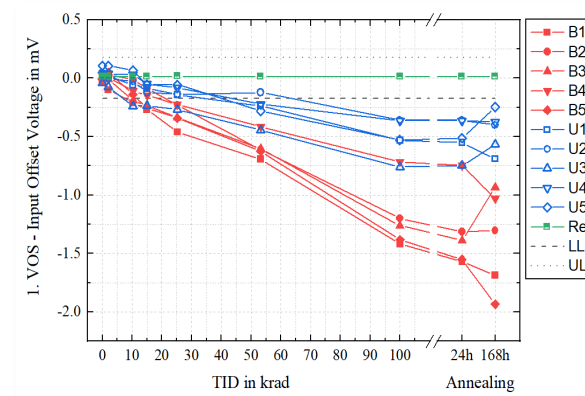
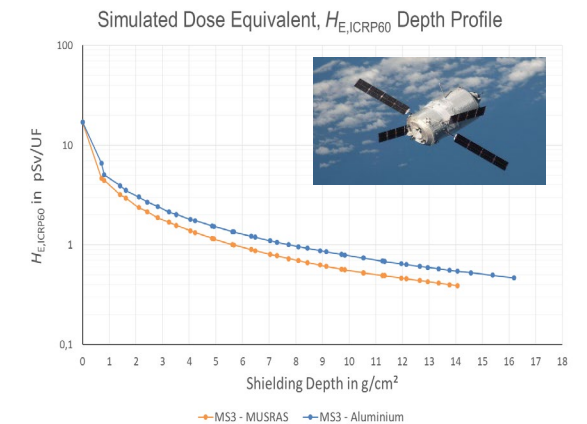
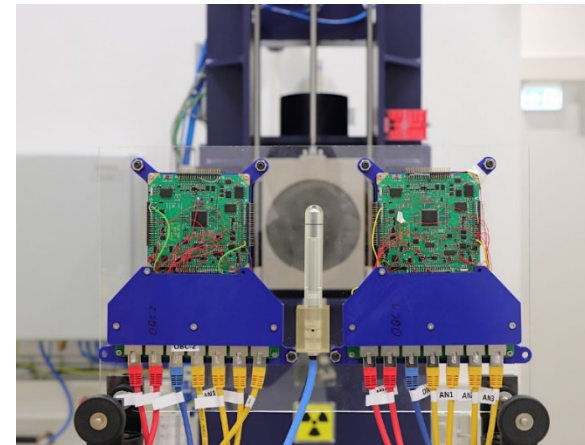


- Environment analysis
- Shielding & dose assessment
- Radiation simulations

Electronics and Consulting



- PCB production (irradiation, testing)
- Set-up and testing equipment
- Support with standards
- Training





Accredited Test House 0312 - Seibersdorf Laboratories EN ISO/IEC 17025



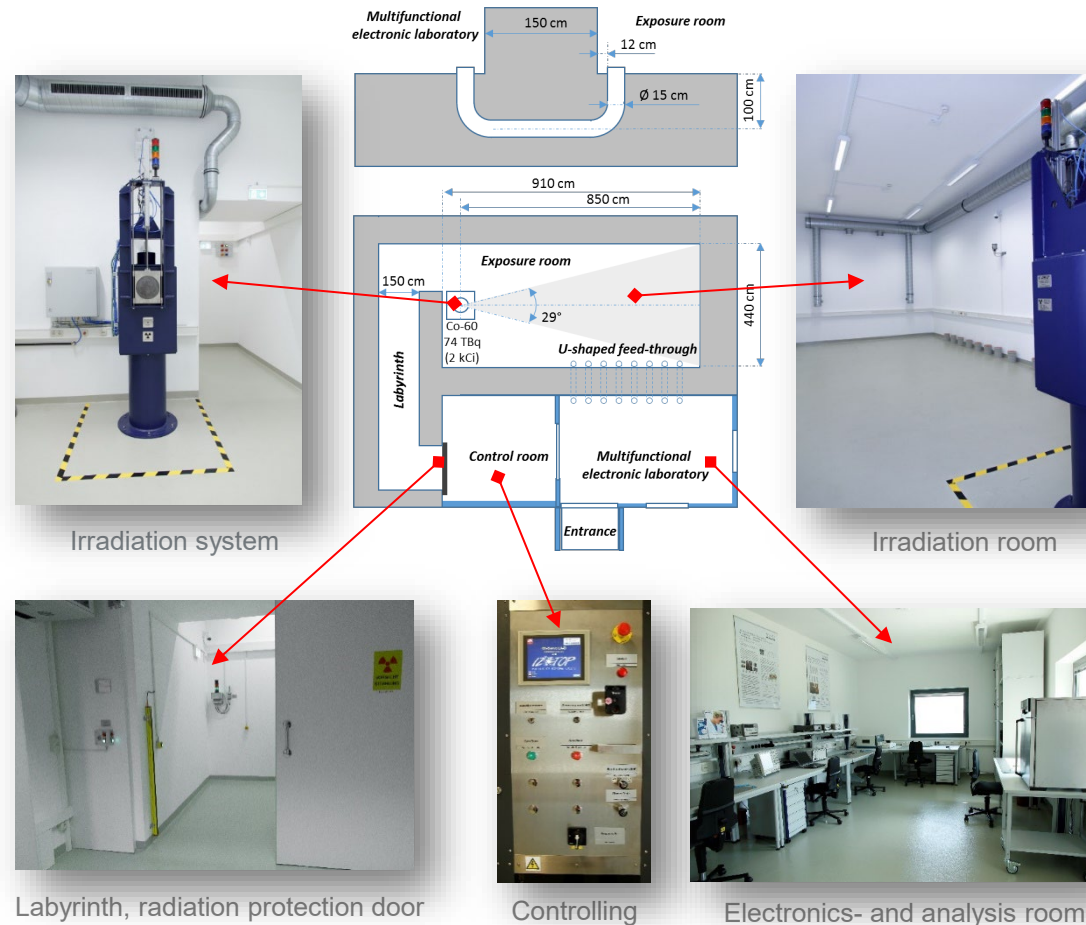
TEC – Laboratory Test of Electronic Components

- Last successful accreditation audit: **October 2025**
- Next accreditation audit: **2026-2027**



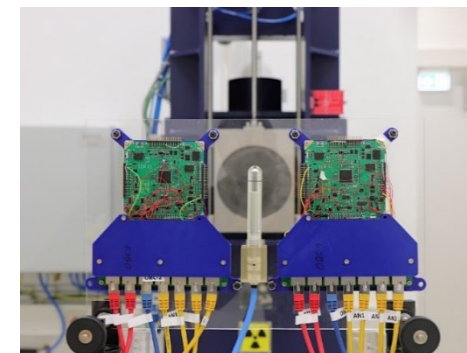
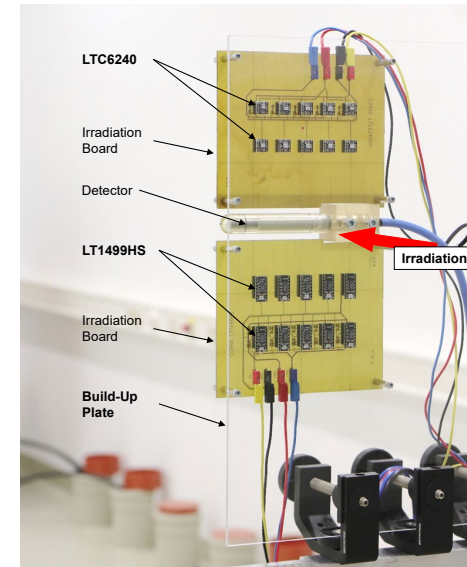
TEC – Laboratory Accredited Testing EN ISO/IEC 17025:2017

EN ISO/IEC 17025 Accredited



TEC-Laboratory

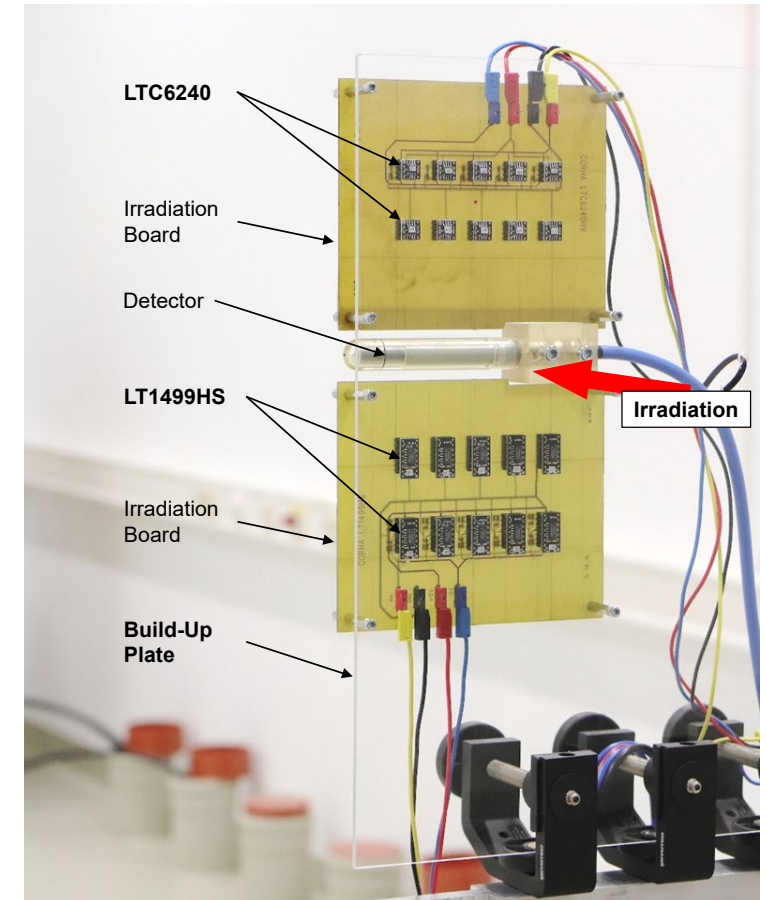
- 24/7 radiation testing services
- Cobalt-60 source 64 TBq
- Dose rate: 50 Gy/h (5 krad/h) \Rightarrow 0.3 Gy/h (<30 rad/h)
- Field size: 10 cm x 10 cm \Rightarrow 100 cm x 100 cm
- ELDRS: 6 months low-dose rate exposure
- Electronic Laboratory attached
- EN ISO/IEC 17025, ECSS, ESCC, MIL-STD



Example: TID Testing of OpAmps

Irradiation Step	Applied Total Dose	Applied Dose Rate
1	2 krad _(Si)	0.6 krad _(Si) /h
2	10 krad _(Si)	
3	15 krad _(Si)	
4	25 krad _(Si)	
5	53 krad _(Si)	
6	100 krad _(Si)	

Annealing Step	Annealing Time	Annealing Temperature
1	24 hours	room temperature
2	168 hours	100°C



Reference: C. Tscherne, M. Wind, M. Bagatin, S. Gerardin, M. Latocha, A. Paccagnella, M. Poizat, P. Beck, *Testing of COTS Operational Amplifier in the Framework of the ESA CORHA Study*, Radiation Effects on Components and Systems Conference, **RADECS 2020**, Nov 2020

Example: Parameter Tests

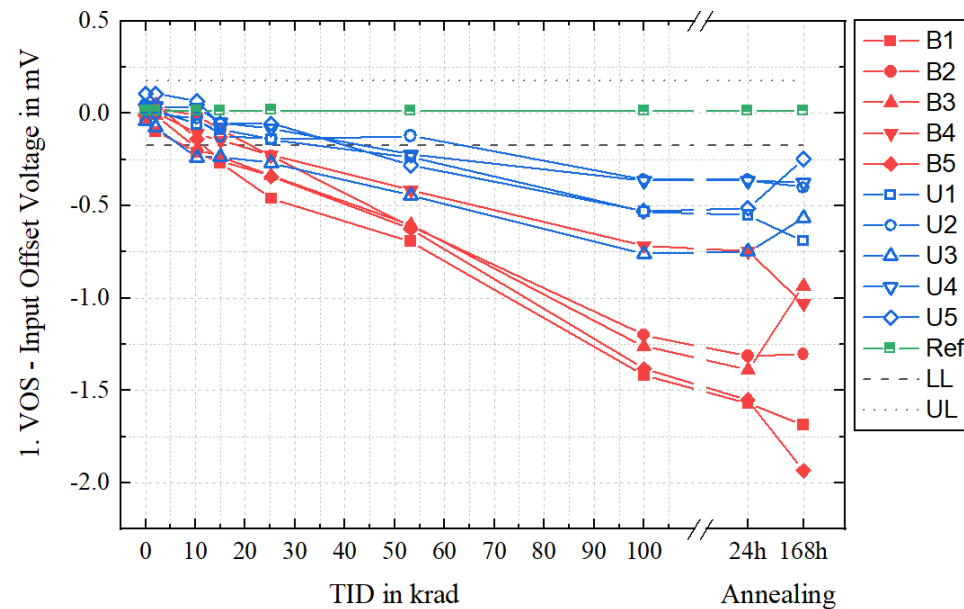
	Symbol	Parameter	LT1499HS		LTC6240		Unit
			Min	Max	Min	Max	
1	V_{OS}	Input Offset Voltage	-800	800	-175	175	μV
2	I_S^+	Positive Supply Current	-	10	-	3.3	mA
3	I_S^-	Negative Supply Current	-	10	-	3.3	mA
4	I_B^+	Input Bias Current at the non-inv. input	-	715	-	0.025	nA
5	I_B^-	Input Bias Current at the inverting input	-	715	-	0.025	nA
6	I_B	Input Bias Current	-	715	-	0.025	nA
7	I_{OS}	Offset Current	-	70	-	0.01	nA
8	A_{VO}	Open Loop Gain	120	-	55	-	dB
9	CMRR	Common Mode Rejection Ratio	93	-	80	-	dB
10	PSRR+	Positive Power Supply Rej. Ratio	89	-	83	-	dB
11	PSRR-	Negative Power Supply Rej. Ratio	N/A	N/A	40	-	dB
12	V_O^+	Positive Output Voltage Swing	14.99	15.00	4.97	5.00	V
13	V_O^-	Negative Output Voltage Swing	-15.00	-14.97	-5.00	-4.97	V
14	I_{SC}^+	Positive Short Circuit Current	-	-15	-	-15	mA
15	I_{SC}^-	Negative Short Circuit Current	30	-	15	-	mA
16	SR+	Positive Slew Rate	3.5	-	5	-	V/ μs
17	SR-	Negative Slew Rate	3.5	-	5	-	V/ μs



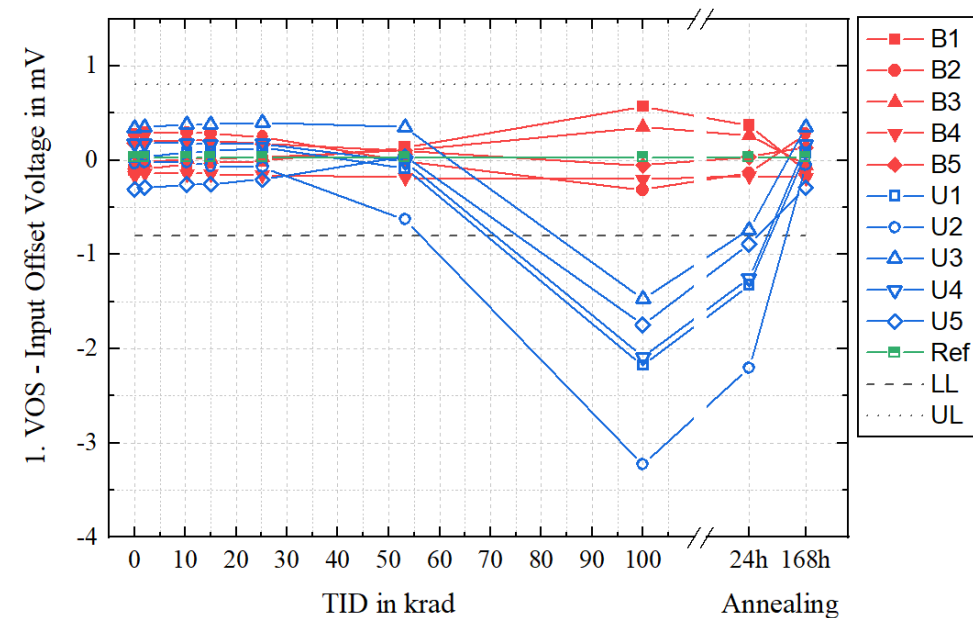
UNIMET Parameter Analyzer

Reference: C. Tscherne, M. Wind, M. Bagatin, S. Gerardin, M. Latocha, A. Paccagnella, M. Poizat, P. Beck, *Testing of COTS Operational Amplifier in the Framework of the ESA CORHA Study*, Radiation Effects on Components and Systems Conference, **RADECS 2020**, Nov 2020

Example: TID Test Results – Input Offset Voltage



Biased devices in red
Unbiased devices in blue
Non-irradiated reference device in green



Reference: C. Tscherne, M. Wind, M. Bagatin, S. Gerardin, M. Latocha, A. Paccagnella, M. Poizat, P. Beck, *Testing of COTS Operational Amplifier in the Framework of the ESA CORHA Study*, Radiation Effects on Components and Systems Conference, **RADECS 2020**, Nov 2020

Example: TID Test Results – Summary

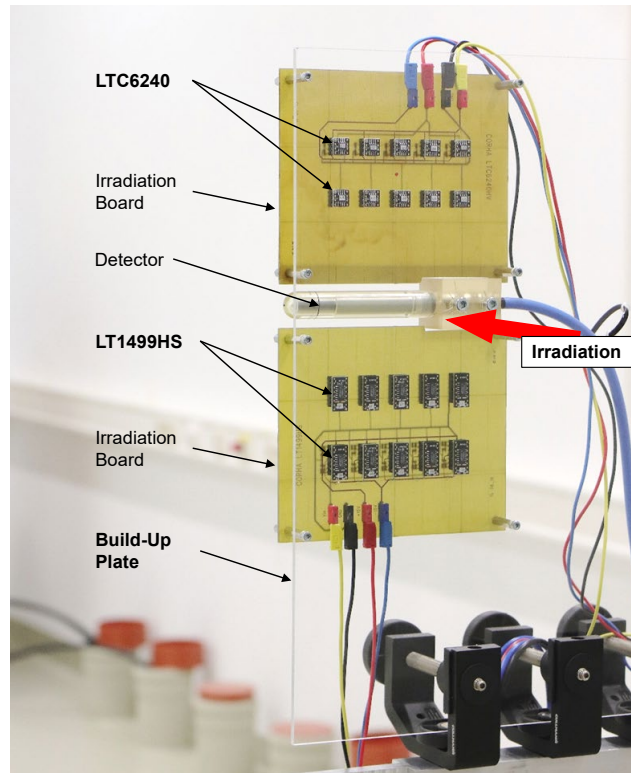
	LTC6240HVCS8								LT1499HS																			
	Applied Dose in krad(Si)						Annealing		Applied Dose in krad(Si)						Annealing													
Symbol	2	10	15	25	53	100	24h R.T.	168h 65°C ¹⁾	2	10	15	25	53	100	24h R.T.	168h 100°C												
V _{os}	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U
I _s ⁺	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U
I _s ⁻	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U
I _B ⁺	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U
I _B ⁻	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U
I _B	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U
I _{os}	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U
A _{vo}	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U
CMRR	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U
V _o ⁺	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U
V _o ⁻	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U
I _{sc} ⁺	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U
I _{sc} ⁻	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U
SR+	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U
SR-	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U
PSRR+	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U
PSRR-	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U	B	U

A green cell color indicates that all biased (B) and unbiased (U) devices are within the specification limits, otherwise the cell is marked red.

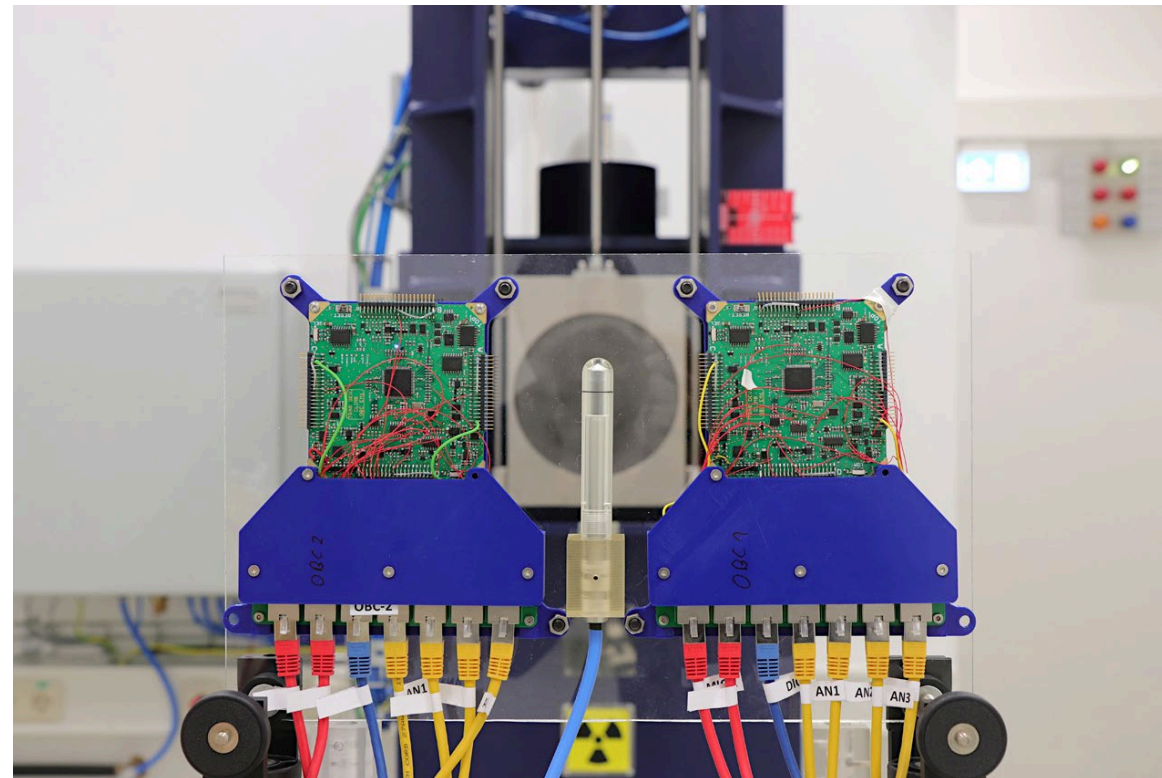
¹⁾ 168 hours annealing is performed at 65°C in order not to exceed the maximum guaranteed operating temperature of 70°C specified in the device's datasheet.

Reference: C. Tscherne, M. Wind, M. Bagatin, S. Gerardin, M. Latocha, A. Paccagnella, M. Poizat, P. Beck, *Testing of COTS Operational Amplifier in the Framework of the ESA CORHA Study*, Radiation Effects on Components and Systems Conference, **RADECS 2020**, Nov 2020

TID Testing on Part and System Level



...On Part Level



...On System Level

Thank you for your attention!



<https://rha.seibersdorf-laboratories.com>

SEIBERSDORF LABORATORIES

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